Features

- Single Voltage Read/Write Operation: 2.65V to 3.6V
- Access Time 70 ns
- Sector Erase Architecture
 - Sixty-three 32K Word (64K Bytes) Sectors with Individual Write Lockout
 - Eight 4K Word (8K Bytes) Sectors with Individual Write Lockout
- Fast Word Program Time 10 μs
- Fast Sector Erase Time 100 ms
- Suspend/Resume Feature for Erase and Program
 - Supports Reading and Programming from Any Sector by Suspending Erase of a Different Sector
 - Supports Reading Any Word by Suspending Programming of Any Other Word
- Low-power Operation
 - 10 mA Active
 - 15 μA Standby
- VPP Pin for Write Protection and Accelerated Program Operation
- WP Pin for Sector Protection
- RESET Input for Device Initialization
- Flexible Sector Protection
- TSOP and CBGA Package Options
- Top or Bottom Boot Block Configuration Available
- 128-bit Protection Register
- Minimum 100,000 Erase Cycles
- Common Flash Interface (CFI)
- · Green (Pb/Halide-free) Packaging

1. Description

The AT49BV320D(T) is a 2.7-volt 32-megabit Flash memory organized as 2,097,152 words of 16 bits each. The memory is divided into 71 sectors for erase operations. The device is offered in a 48-lead TSOP package and a 47-ball CBGA package. The device has $\overline{\text{CE}}$ and $\overline{\text{OE}}$ control signals to avoid any bus contention. This device can be read or reprogrammed using a single power supply, making it ideally suited for in-system programming.

The device powers on in the read mode. Command sequences are used to place the device in other operation modes such as program and erase. The device has the capability to protect the data in any sector (see "Flexible Sector Protection" on page 6).

To increase the flexibility of the device, it contains an Erase Suspend and Program Suspend feature. This feature will put the erase or program on hold for any amount of time and let the user read data from or program data to any of the remaining sectors within the memory.

The VPP pin provides data protection. When the V_{PP} input is below 0.4V, the program and erase functions are inhibited. When V_{PP} is at 1.65V or above, normal program and erase operations can be performed. With V_{PP} at 10.0V, the program (Dual-word Program command) operation is accelerated.



32-megabit (2M x 16) 3-volt Only Flash Memory

AT49BV320D AT49BV320DT

Not Recommended for New Design

Contact Atmel to discuss the latest design in trends and options

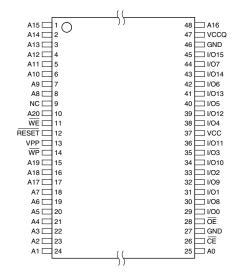




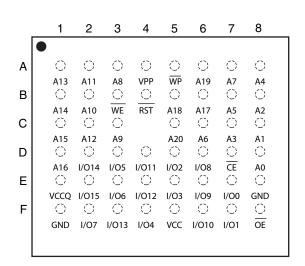
2. Pin Configurations

Pin Name	Function	
A0 - A20	Addresses	
CE	Chip Enable	
ŌĒ	Output Enable	
WE	Write Enable	
RESET	Reset	
VPP	Write Protection	
I/O0 - I/O15	Data Inputs/Outputs	
NC	No Connect	
VCCQ	Output Power Supply	
WP	Write Protect	

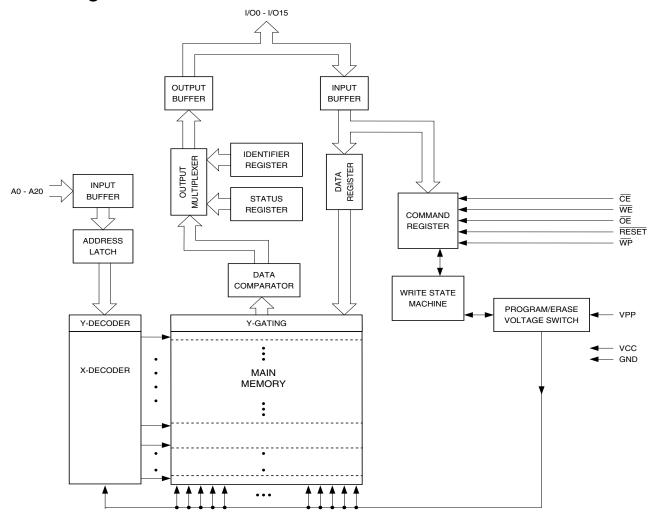
2.1 TSOP Top View (Type 1)



2.2 CBGA Top View (Ball Down)



3. Block Diagram



4. Device Operation

4.1 Command Sequences

When the device is first powered on, it will be in the read mode. In order to perform other device functions, a series of command sequences are entered into the device. The command sequences are shown in the "Command Definition Table" on page 15 (I/O8 - I/O15 are don't care inputs for the command codes). The command sequences are written by applying a low pulse on the $\overline{\text{WE}}$ or $\overline{\text{CE}}$ input with $\overline{\text{CE}}$ or $\overline{\text{WE}}$ low (respectively) and $\overline{\text{OE}}$ high. The address and data are latched by the first rising edge of $\overline{\text{CE}}$ or $\overline{\text{WE}}$. Standard microprocessor write timings are used. The address locations used in the command sequences are not affected by entering the command sequences.

4.2 Read

When the AT49BV320D(T) is in the read mode, with \overline{CE} and \overline{OE} low and \overline{WE} high, the data stored at the memory location determined by the address pins are asserted on the outputs. The





outputs are put in the high impedance state whenever \overline{CE} or \overline{OE} is high. This dual-line control gives designers flexibility in preventing bus contention.

4.3 Reset

A RESET input pin is provided to ease some system applications. When RESET is at a logic high level, the device is in its standard operating mode. A low level on the RESET input halts the present device operation and puts the outputs of the device in a high impedance state. When a high level is reasserted on the RESET pin, the device returns to the read mode, depending upon the state of the control inputs.

4.4 Erase

Before a word can be reprogrammed, it must be erased. The erased state of memory bits is a logical "1". The individual sectors can be erased by using the Sector Erase command.

4.4.1 Sector Erase

The device is organized into 71 sectors (SA0 - SA70) that can be individually erased. The Sector Erase command is a two-bus cycle operation. The sector address and the D0H Data Input command are latched on the rising edge of $\overline{\text{WE}}$. The sector erase starts after the rising edge of $\overline{\text{WE}}$ of the second cycle provided the given sector has not been protected. The erase operation is internally controlled; it will automatically time to completion. The maximum time to erase a sector is t_{SEC} . An attempt to erase a sector that has been protected will result in the operation terminating immediately.

4.5 Word Programming

Once a memory sector is erased, it is programmed (to a logical "0") on a word-by-word basis. Programming is accomplished via the Internal Device command register and is a two-bus cycle operation. The device will automatically generate the required internal program pulses.

Any commands, except Read Status Register, Program Suspend and Program Resume, written to the chip during the embedded programming cycle will be ignored. If a hardware reset happens during programming, the data at the location being programmed will be corrupted. Please note that a data "0" cannot be programmed back to a "1"; only erase operations can convert "0"s to "1"s. Programming is completed after the specified t_{BP} cycle time. If the program status bit is a "1", the device was not able to verify that the program operation was performed successfully. The status register indicates the programming status. While the program sequence executes, status bit I/O7 is "0".

4.6 VPP Pin

The circuitry of the AT49BV320D(T) is designed so that the device cannot be programmed or erased if the V_{PP} voltage is less that 0.4V. When V_{PP} is at 1.65V or above, normal program and erase operations can be performed. The VPP pin cannot be left floating.

4.7 Read Status Register

The status register indicates the status of device operations and the success/failure of that operation. The Read Status Register command causes subsequent reads to output data from the status register until another command is issued. To return to reading from the memory, issue a Read command.

The status register bits are output on I/O7 - I/O0. The upper byte, I/O15 - I/O8, outputs 00H when a Read Status Register command is issued.

The contents of the status register [SR7:SR0] are latched on the falling edge of \overline{OE} or \overline{CE} (whichever occurs last), which prevents possible bus errors that might occur if status register contents change while being read. \overline{CE} or \overline{OE} must be toggled with each subsequent status read, or the status register will not indicate completion of a Program or Erase operation.

When the Write State Machine (WSM) is active, SR7 will indicate the status of the WSM; the remaining bits in the status register indicate whether the WSM was successful in performing the preferred operation (see Table 4-1).

 Table 4-1.
 Status Register Bit Definition

WSMS	ESS	ES	PS	VPPS	PSS	SLS	R
7	6	5	4	3	2	1	0
					No	otes	
SR7 WRITE ST 1 = Ready 0 = Busy	_					irst to determine \ ore checking proo	
1 = Erase Susp	SR6 = ERASE SUSPEND STATUS (ESS) 1 = Erase Suspended 0 = Erase In Progress/Completed			both WSMS an		, WSM halts exec – ESS bit remain issued.	
1 = Error in Sec	SR5 = ERASE STATUS (ES) 1 = Error in Sector Erase 0 = Successful Sector Erase					has applied the r s still unable to ve	
1 = Error in Pro	SR4 = PROGRAM STATUS (PS) 1 = Error in Programming 0 = Successful Programming			When this bit is program a word		has attempted bu	ut failed to
SR3 = VPP STATUS (VPPS) 1 = VPP Low Detect, Operation Abort 0 = VPP OK		level. The WSN Erase comman system if V _{PP} ha	/l interrogates V _P d sequences hav	ide continuous in P level only after to be been entered a ched on. The V _{PP} by the WSM.	the Program or and informs the		
SR2 = PROGRAM SUSPEND STATUS (PSS) 1 = Program Suspended 0 = Program in Progress/Completed		sets both WSM		ed, WSM halts ex o "1". PSS bit ren and is issued.			
1 = Prog/Erase	SR1 = SECTOR LOCK STATUS (SLS) 1 = Prog/Erase attempted on a locked sector; Operation aborted. 0 = No operation to locked sectors		sectors, this bit	is set by the WS	is attempted to or M. The operation ed to read status	specified is	
SR0 = RESERVED FOR FUTURE ENHANCEMENTS (R)			ved for future use e status register.	e and should be r	masked out		

Note: 1. A Command Sequence Error is indicated when SR1, SR3, SR4 and SR5 are set.





4.7.1 Clear Status Register

The WSM can set status register bits 1 through 7 and can clear bits 2, 6 and 7; but, the WSM cannot clear status register bits 1, 3, 4 or 5. Because bits 1, 3, 4 and 5 indicate various error conditions, these bits can be cleared only through the Clear Status Register command. By allowing the system software to control the resetting of these bits, several operations may be performed (such as cumulatively programming several addresses or erasing multiple sectors in sequence) before reading the status register to determine if an error occurred during those operations. The status register should be cleared before beginning another operation. The Read command must be issued before data can be read from the memory array. The status register can also be cleared by resetting the device.

4.8 Flexible Sector Protection

The AT49BV320D(T) offers two sector protection modes, the Softlock and the Hardlock. The Softlock mode is optimized as sector protection for sectors whose content changes frequently. The Hardlock protection mode is recommended for sectors whose content changes infrequently. Once either of these two modes is enabled, the contents of the selected sector is read-only and cannot be erased or programmed. Each sector can be independently programmed for either the Softlock or Hardlock sector protection mode. At power-up and reset, all sectors have their Softlock protection mode enabled.

4.8.1 Softlock and Unlock

The Softlock protection mode can be disabled by issuing a two-bus cycle Unlock command to the selected sector. Once a sector is unlocked, its contents can be erased or programmed. To enable the Softlock protection mode, a two-bus cycle Softlock command must be issued to the selected sector.

4.8.2 Hardlock and Write Protect

The Hardlock sector protection mode operates in conjunction with the Write Protect ($\overline{\text{WP}}$) pin. The Hardlock sector protection mode can be enabled by issuing a two-bus cycle Hardlock Software command to the selected sector. The state of the Write Protect pin affects whether the Hardlock protection mode can be overridden.

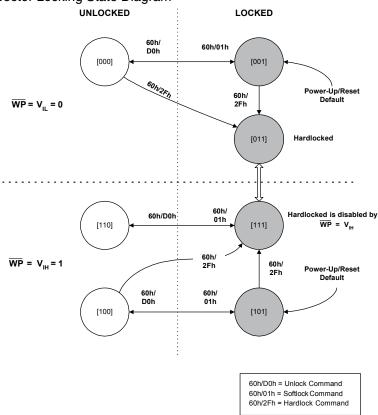
- When the WP pin is low and the Hardlock protection mode is enabled, the sector cannot be unlocked and the contents of the sector is read-only.
- When the WP pin is high, the Hardlock protection mode is overridden and the sector can be unlocked via the Unlock command.

To disable the Hardlock sector protection mode, the chip must be either reset or power cycled.

Table 4-2. Hardlock and Softlock Protection Configurations in Conjunction with WP

V _{PP}	WP	Hard- lock	Soft- lock	Erase/ Prog Allowed?	Comments
V _{CC} /5V	0	0	0	Yes	No sector is locked
V _{CC} /5V	0	0	1	No	Sector is Softlocked. The Unlock command can unlock the sector.
V _{CC} /5V	0	1	1	No	Hardlock protection mode is enabled. The sector cannot be unlocked.
V _{CC} /5V	1	0	0	Yes	No sector is locked.
V _{CC} /5V	1	0	1	No	Sector is Softlocked. The Unlock command can unlock the sector.
V _{CC} /5V	1	1	0	Yes	Hardlock protection mode is overridden and the sector is not locked.
V _{CC} /5V	1	1	1	No	Hardlock protection mode is overridden and the sector can be unlocked via the Unlock command.
V _{IL}	х	х	х	No	Erase and Program Operations cannot be performed.

Figure 4-1. Sector Locking State Diagram



Note: 1. The notation [X, Y, Z] denotes the locking state of a sector. The current locking state of a sector is defined by the state of WP and the two bits of the sector-lock status D[1:0].





4.8.3 Sector Protection Detection

A software method is available to determine if the sector protection Softlock or Hardlock features are enabled. When the device is in the software product identification mode, a read from the I/O0 and I/O1 at address location 00002H within a sector will show if the sector is unlocked, softlocked, or hardlocked.

Table 4-3. Sector Protection Status

I/O1	I/O0	Sector Protection Status
0	0	Sector Not Locked
0	1	Softlock Enabled
1	0	Hardlock Enabled
1	1	Both Hardlock and Softlock Enabled

4.9 Erase Suspend/Erase Resume

The Erase Suspend command allows the system to interrupt a sector erase operation and then program or read data from a different sector within the memory. After the Erase Suspend command is given, the device requires a maximum time of 15 µs to suspend the erase operation. After the erase operation has been suspended, the system can then read data or program data to any other sector within the device. An address is not required during the Erase Suspend command. During a sector erase suspend, another sector cannot be erased. To resume the sector erase operation, the system must write the Erase Resume command. The Erase Resume command is a one-bus cycle command. The only valid commands while erase is suspended are Read Status Register, Product ID Entry, CFI Query, Program, Program Resume, Erase Resume, Sector Softlock/Hardlock, Sector Unlock.

4.10 Program Suspend/Program Resume

The Program Suspend command allows the system to interrupt a programming operation and then read data from a different word within the memory. After the Program Suspend command is given, the device requires a maximum of 20 µs to suspend the programming operation. After the programming operation has been suspended, the system can then read data from any other word within the device. An address is not required during the program suspend operation. To resume the programming operation, the system must write the Program Resume command. The program suspend and resume are one-bus cycle commands. The command sequence for the erase suspend and program suspend are the same and the command sequence for the erase resume and program resume are the same. The only other valid commands while program is suspended are Read Status Register, Product ID Entry, CFI Query and Program Resume.

4.11 Product Identification

The product identification mode identifies the device and manufacturer as Atmel. It may be accessed by a software operation. For details, see "Operating Modes" on page 21.

4.12 128-bit Protection Register

The AT49BV320D(T) contains a 128-bit register that can be used for security purposes in system design. The protection register is divided into two 64-bit sectors. The two sectors are designated as sector A and sector B. The data in sector A is non-changeable and is programmed at the factory with a unique number. The data in sector B is programmed by the user and can be locked out such that data in the sector cannot be reprogrammed. To program sector

B in the protection register, the two-bus cycle Program Protection Register command must be used as shown in the "Command Definition Table" on page 15. To lock out sector B, the two-bus cycle Lock Protection Register command must be used as shown in the "Command Definition Table". Data bit D1 must be zero during the second bus cycle. All other data bits during the second bus cycle are don't cares. To determine whether sector B is locked out, use the status of sector B protection command. If data bit D1 is zero, sector B is locked. If data bit D1 is one, sector B can be reprogrammed. Please see the "Protection Register Addressing Table" on page 16 for the address locations in the protection register. To read the protection register, the Product ID Entry command is given followed by a normal read operation from an address within the protection register. After determining whether sector B is protected or not, or reading the protection register, the Read command must be given to return to the read mode.

4.13 Common Flash Interface (CFI)

CFI is a published, standardized data structure that may be read from a flash device. CFI allows system software to query the installed device to determine the configurations, various electrical and timing parameters and functions supported by the device. CFI is used to allow the system to learn how to interface to the flash device most optimally. The two primary benefits of using CFI are ease of upgrading and second source availability. The command to enter the CFI Query mode is a one-bus cycle command which requires writing data 98h to any address. The CFI Query command can be written when the device is ready to read data or can also be written when the part is in the product ID mode. Once in the CFI Query mode, the system can read CFI data at the addresses given in "Common Flash Interface Definition Table" on page 27. To return to the read mode, issue the Read command.

4.14 Hardware Data Protection

The Hardware Data Protection feature protects against inadvertent programs to the AT49BV320D(T) in the following ways: (a) V_{CC} sense: if V_{CC} is below 1.8V (typical), the program function is inhibited. (b) V_{CC} power-on delay: once V_{CC} has reached the V_{CC} sense level, the device will automatically time out 10 ms (typical) before programming. (c) Program inhibit: holding any one of \overline{OE} low, \overline{CE} high or \overline{WE} high inhibits program cycles. (d) Program inhibit: V_{PP} is less than V_{IIPP} .

4.15 Input Levels

While operating with a 2.65V to 3.6V power supply, the address inputs and control inputs $(\overline{OE}, \overline{CE})$ and \overline{WE}) may be driven from 0 to 5.5V without adversely affecting the operation of the device. The I/O lines can only be driven from 0 to V_{CCO} + 0.6V.

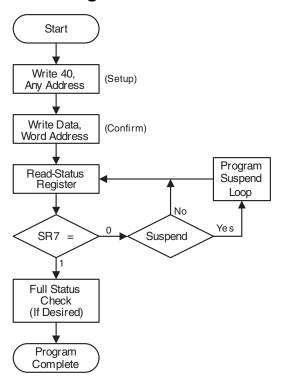
4.16 Output Levels

For the AT49BV320D(T), output high levels (V_{OH}) are equal to V_{CCQ} - 0.1V (not V_{CC}). For 2.65V - 3.6V output levels, V_{CCQ} must be tied to V_{CC} .





5. Word Program Flowchart



6. Word Program Procedure

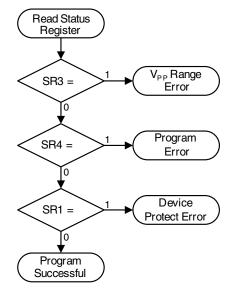
Bus Operation	Command	Comments
Write	Program Setup	Data = 40 Addr = Any Address
Write	Data	Data = Data to program Addr = Location to program
Read	None	Status register data: Toggle \overline{CE} or \overline{OE} to update status register
Idle	None	Check SR7 1 = WSM Ready 0 = WSM Busy

Repeat for subsequent Word Program operations.

Full status register check can be done after each program, or after a sequence of program operations.

Write FF after the last operation to set to the Read state.

7. Full Status Check Flowchart



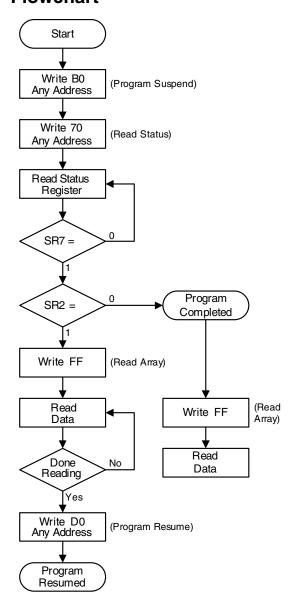
8. Full Status Check Procedure

Bus Operation	Command	Comments
Idle	None	Check SR3: 1 = V _{PP} Error
Idle	None	Check SR4: 1 = Data Program Error
Idle	None	Check SR1: 1 = Sector locked; operation aborted

SR3 MUST be cleared before the Write State Machine allows further program attempts.

If an error is detected, clear the status register before continuing operations – only the Clear Status Register command clears the status register error bits.

9. Program Suspend/Resume Flowchart

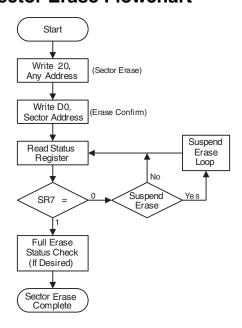


10. Program Suspend/Resume Procedure

1 TOCEGUIE		
Bus Operation	Command	Comments
Write	Program Suspend	Data = B0 Addr = Any address
Write	Read Status	Data = 70 Addr = Any address
Read	None	Status register data: Toggle \overline{CE} or \overline{OE} to update status register Addr = Any address
ldle	None	Check SR7 1 = WSM Ready 0 = WSM Busy
ldle	None	Check SR2 1 = Program suspended 0 = Program completed
Write	Read Array	Data = FF Addr = Any address
Read	None	Read data from any word in the memory
Write	Program Resume	Data = D0 Addr = Any address



11. Sector Erase Flowchart



12. Sector Erase Procedure

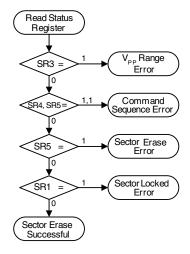
Bus Operation	Command	Comments
Write	Sector Erase Setup	Data = 20 Addr = Any address
Write	Erase Confirm	Data = D0 Addr = Sector to be erased (SA)
Read	None	Status register data: Toggle CE or OE to update status register data
Idle	None	Check SR7 1 = WSM Ready 0 = WSM Busy

Repeat for subsequent sector erasures.

Full status register check can be done after each sector erase, or after a sequence of sector erasures.

Write FF after the last operation to enter read mode.

13. Full Erase Status Check Flowchart



14. Full Erase Status Check Procedure

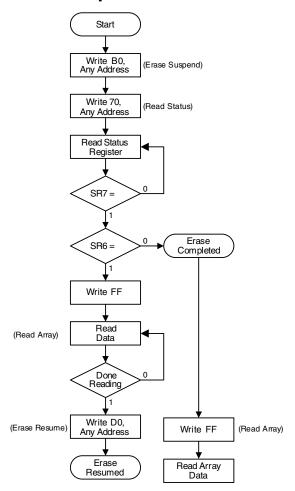
Bus Operation	Command	Comments	
Idle	None	Check SR3: 1 = V _{PP} Range Error	
Idle	None	Check SR4, SR5: Both 1 = Command Sequence Error	
Idle	None	Check SR5: 1 = Sector Erase Error	
Idle	None	Check SR1: 1 = Attempted erase of locked sector; erase aborted.	

SR1, SR3 must be cleared before the Write State Machine allows further erase attempts.

Only the Clear Status Register command clears SR1, SR3, SR4, SR5.

If an error is detected, clear the status register before attempting an erase retry or other error recovery.

15. Erase Suspend/Resume Flowchart



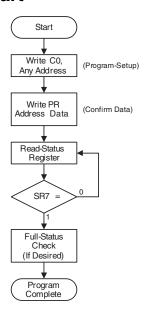
16. Erase Suspend/Resume Procedure

Bus Operation	Command	Comments
Write	Erase Suspend	Data = B0 Addr = Any address
Write	Read Status	Data = 70 Addr = Any address
Read	None	Status register data: Toggle \overline{CE} or \overline{OE} to update status register Addr = Any address
Idle	None	Check SR7 1 = WSM Ready 0 = WSM Busy
Idle	None	Check SR6 1 = Erase suspended 0 = Erase completed
Write	Read or Program	Data = FF or 40 Addr = Any address
Read or Write	None	Read or program data from/to sector other than the one being erased
Write	Program Resume	Data = D0 Addr = Any address





17. Protection Register Programming Flowchart



18. Protection Register Programming Procedure

Bus Operation	Command	Comments
Write	Program PR Setup	Data = C0 Addr = Any address
Write	Protection Program	Data = Data to Program Addr = Location to Program
Read	None	Status register data: Toggle CE or OE to update status register data
Idle	None	Check SR7 1 = WSM Ready 0 = WSM Busy

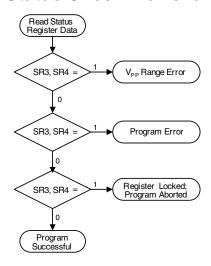
Program Protection Register operation addresses must be within the protection register address space. Addresses outside this space will return an error.

Repeat for subsequent programming operations.

Full status register check can be done after each program, or after a sequence of program operations.

Write FF after the last operation to return to the Read mode.

19. Full Status Check Flowchart



20. Full Status Check Procedure

Bus Operation	Command	Comments
Idle	None	Check SR1, SR3, SR4: 0,1,1 = V _{PP} Range Error
Idle	None	Check SR1, SR3, SR4: 0,0,1 = Programming Error
Idle	None	Check SR1, SR3, SR4: 1, 0,1 = Sector locked; operation aborted

SR3 must be cleared before the Write State Machine allows further program attempts.

Only the Clear Status Register command clears SR1, SR3, SR4.

If an error is detected, clear the status register before attempting a program retry or other error recovery.

21. Command Definition Table

	Bus		Bus /cle	2nd Bus Cycle		3rd Bus Cycle	
Command Sequence	Cycles	Addr	Data	Addr	Data	Addr	Data
Read	1	XX	FF				
Sector Erase/Confirm	2	XX	20	SA ⁽²⁾	D0		
Word Program	2	XX	40/10	Addr	D _{IN}		
Dual-word Program ⁽³⁾	3	XX	E0	Addr0	D _{INO}	Addr1	D _{IN1}
Erase/Program Suspend	1	XX	В0				
Erase/Program Resume	1	XX	D0				
Product ID Entry	1	XX	90				
Sector Softlock	2	XX	60	SA ⁽²⁾	01		
Sector Hardlock	2	XX	60	SA ⁽²⁾	2F		
Sector Unlock	2	XX	60	SA ⁽²⁾	D0		
Read Status Register	2	XX	70	XX	D _{OUT} ⁽⁴⁾		
Clear Status Register	1	XX	50				
Program Protection Register	2	XX	C0	Addr ⁽⁵⁾	D _{IN}		
Lock Protection Register – Sector B	2	XX	C0	80	FFFD		
Status of Sector B Protection	2	XX	90	80	D _{OUT} ⁽⁶⁾		
CFI Query	1	XX	98				

Notes:

- 1. The DATA FORMAT shown for each bus cycle is as follows; I/O7 I/O0 (Hex). I/O15 I/O8 are don't care. The ADDRESS FORMAT shown for each bus cycle is as follows: A7 A0 (Hex). Address A20 through A8 are don't care.
- 2. SA = sector address. Any word address within a sector can be used to designate the sector address (see pages 17 20 for details).
- 3. This fast programming option enables the user to program two words in parallel only when $V_{PP} = 9.5V$. The addresses, Addr0 and Addr1, of the two words, D_{IN0} and D_{IN1} , must only differ in address A0. This command should be used during manufacturing purposes only.
- 4. The status register bits are output on I/O7 I/O0.
- Any addresses within the user programmable protection register region. Address locations are shown on "Protection Register Addressing Table" on page 16.
- 6. If data bit D1 is "0", sector B is locked. If data bit D1 is "1", sector B can be reprogrammed.

22. Absolute Maximum Ratings*

Temperature under Bias55°C to +125°	,C
Storage Temperature65°C to +150°	Ò,
All Input Voltages (including NC Pins) with Respect to Ground0.6V to +6.25	šV
All Output Voltages with Respect to Ground0.6V to V _{CC} + 0.6	SV
Voltage on V _{PP} with Respect to Ground0.6V to +10.0)V

*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





23. Protection Register Addressing Table

Address	Use	Sector	A 7	A 6	A 5	A 4	А3	A2	A 1	A0
81	Factory	Α	1	0	0	0	0	0	0	1
82	Factory	Α	1	0	0	0	0	0	1	0
83	Factory	Α	1	0	0	0	0	0	1	1
84	Factory	Α	1	0	0	0	0	1	0	0
85	User	В	1	0	0	0	0	1	0	1
86	User	В	1	0	0	0	0	1	1	0
87	User	В	1	0	0	0	0	1	1	1
88	User	В	1	0	0	0	1	0	0	0

Note: All address lines not specified in the above table must be "0" when accessing the protection register, i.e., A20 - A8 = 0.

24. AT49BV320D Sector Address Table

Sector	Size (Bytes/Words) Address Range (A20 - A0)	
SA0	8K/4K	00000 - 00FFF
SA1	8K/4K	01000 - 01FFF
SA2	8K/4K	02000 - 02FFF
SA3	8K/4K	03000 - 03FFF
SA4	8K/4K	04000 - 04FFF
SA5	8K/4K	05000 - 05FFF
SA6	8K/4K	06000 - 06FFF
SA7	8K/4K	07000 - 07FFF
SA8	64K/32K	08000 - 0FFFF
SA9	64K/32K	10000 - 17FFF
SA10	64K/32K	18000 - 1FFFF
SA11	64K/32K	20000 - 27FFF
SA12	64K/32K	28000 - 2FFFF
SA13	64K/32K	30000 - 37FFF
SA14	64K/32K	38000 - 3FFFF
SA15	64K/32K	40000 - 47FFF
SA16	64K/32K	48000 - 4FFFF
SA17	64K/32K	50000 - 57FFF
SA18	64K/32K	58000 - 5FFFF
SA19	64K/32K	60000 - 67FFF
SA20	64K/32K	68000 - 6FFFF
SA21	64K/32K	70000 - 77FFF
SA22	64K/32K	78000 - 7FFFF
SA23	64K/32K	80000 - 87FFF
SA24	64K/32K	88000 - 8FFFF
SA25	64K/32K	90000 - 97FFF
SA26	64K/32K	98000 - 9FFFF
SA27	64K/32K	A0000 - A7FFF
SA28	64K/32K	A8000 - AFFFF
SA29	64K/32K	B0000 - B7FFF
SA30	64K/32K	B8000 - BFFFF
SA31	64K/32K	C0000 - C7FFF
SA32	64K/32K	C8000 - CFFFF
SA33	64K/32K	D0000 - D7FFF
SA34	64K/32K	D8000 - DFFFF
SA35	64K/32K	E0000 - E7FFF
SA36	64K/32K	E8000 - EFFFF
SA37	64K/32K	F0000 - F7FFF





24. AT49BV320D Sector Address Table (Continued)

Sector	Size (Bytes/Words)	Address Range (A20 - A0)
SA38	64K/32K	F8000 - FFFFF
SA39	64K/32K	100000 - 107FFF
SA40	64K/32K	108000 - 10FFFF
SA41	64K/32K	110000 - 117FFF
SA42	64K/32K	118000 - 11FFFF
SA43	64K/32K	120000 - 127FFF
SA44	64K/32K	128000 - 12FFFF
SA45	64K/32K	130000 - 137FFF
SA46	64K/32K	138000 - 13FFFF
SA47	64K/32K	140000 - 147FFF
SA48	64K/32K	148000 - 14FFFF
SA49	64K/32K	150000 - 157FFF
SA50	64K/32K	158000 - 15FFFF
SA51	64K/32K	160000 - 167FFF
SA52	64K/32K	168000 - 16FFFF
SA53	64K/32K	170000 - 177FFF
SA54	64K/32K	178000 - 17FFFF
SA55	64K/32K	180000 - 187FFF
SA56	64K/32K	188000 - 18FFFF
SA57	64K/32K	190000 - 197FFF
SA58	64K/32K	198000 - 19FFFF
SA59	64K/32K	1A0000 - 1A7FFF
SA60	64K/32K	1A8000 - 1AFFFF
SA61	64K/32K	1B0000 - 1B7FFF
SA62	64K/32K	1B8000 - 1BFFFF
SA63	64K/32K	1C0000 - 1C7FFF
SA64	64K/32K	1C8000 - 1CFFFF
SA65	64K/32K	1D0000 - 1D7FFF
SA66	64K/32K	1D8000 - 1DFFFF
SA67	64K/32K	1E0000 - 1E7FFF
SA68	64K/32K	1E8000 - 1EFFFF
SA69	64K/32K	1F0000 -1F7FFF
SA70	64K/32K	1F8000 - 1FFFFF
	I .	

25. AT49BV320DT - Sector Address Table

Sector	Size (Bytes/Words)	Address Range (A20 - A0)
SA0	64K/32K	00000 - 07FFF
SA1	64K/32K	08000 - 0FFFF
SA2	64K/32K	10000 - 17FFF
SA3	64K/32K	18000 - 1FFFF
SA4	64K/32K	20000 - 27FFF
SA5	64K/32K	28000 - 2FFFF
SA6	64K/32K	30000 - 37FFF
SA7	64K/32K	38000 - 3FFFF
SA8	64K/32K	40000 - 47FFF
SA9	64K/32K	48000 - 4FFFF
SA10	64K/32K	50000 - 57FFF
SA11	64K/32K	58000 - 5FFFF
SA12	64K/32K	60000 - 67FFF
SA13	64K/32K	68000 - 6FFFF
SA14	64K/32K	70000 - 77FFF
SA15	64K/32K	78000 - 7FFFF
SA16	64K/32K	80000 - 87FFF
SA17	64K/32K	88000 - 8FFFF
SA18	64K/32K	90000 - 97FFF
SA19	64K/32K	98000 - 9FFFF
SA20	64K/32K	A0000 - A7FFF
SA21	64K/32K	A8000 - AFFFF
SA22	64K/32K	B0000 - B7FFF
SA23	64K/32K	B8000 - BFFFF
SA24	64K/32K	C0000 - C7FFF
SA25	64K/32K	C8000 - CFFFF
SA26	64K/32K	D0000 - D7FFF
SA27	64K/32K	D8000 - DFFFF
SA28	64K/32K	E0000 - E7FFF
SA29	64K/32K	E8000 - EFFFF
SA30	64K/32K	F0000 - F7FFF
SA31	64K/32K	F8000 - FFFFF
SA32	64K/32K	100000 - 107FFF
SA33	64K/32K	108000 - 10FFFF
SA34	64K/32K	110000 - 117FFF
SA35	64K/32K	118000 - 11FFFF
SA36	64K/32K	120000 - 127FFF
SA37	64K/32K	128000 - 12FFFF





25. AT49BV320DT – Sector Address Table (Continued)

SA38 64K/32K 130000 - 137FFF SA39 64K/32K 138000 - 13FFFF SA40 64K/32K 140000 - 147FFF SA41 64K/32K 148000 - 14FFFF SA42 64K/32K 150000 - 157FFF SA43 64K/32K 158000 - 15FFFF SA44 64K/32K 160000 - 167FFF SA45 64K/32K 160000 - 177FFF SA46 64K/32K 178000 - 177FFF SA48 64K/32K 178000 - 177FFF SA49 64K/32K 188000 - 18FFFF SA50 64K/32K 19000 - 197FFF SA51 64K/32K 19000 - 197FFF SA52 64K/32K 19800 - 19FFFF SA53 64K/32K 19800 - 18FFFF SA53 64K/32K 18000 - 18FFF SA54 64K/32K 18000 - 10FFFF SA53 64K/32K 18000 - 10FFFF SA54 64K/32K 18000 - 10FFFF SA55 64K/32K 18000 - 10FFFF SA56 64K/32K 100000	
SA40 64K/32K 140000 - 147FFF SA41 64K/32K 148000 - 14FFFF SA42 64K/32K 150000 - 157FFF SA43 64K/32K 158000 - 15FFFF SA44 64K/32K 160000 - 167FFF SA45 64K/32K 168000 - 16FFFF SA46 64K/32K 170000 - 177FFF SA47 64K/32K 178000 - 17FFFF SA48 64K/32K 180000 - 187FFF SA49 64K/32K 188000 - 18FFFF SA50 64K/32K 190000 - 197FFF SA51 64K/32K 198000 - 19FFFF SA52 64K/32K 198000 - 19FFFF SA53 64K/32K 1A0000 - 1AFFFF SA54 64K/32K 1B0000 - 1BFFFF SA55 64K/32K 1B0000 - 1BFFFF SA56 64K/32K 1B0000 - 1DFFFF SA57 64K/32K 1C0000 - 1CFFFF SA58 64K/32K 1D0000 - 1DFFFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E8000 - 1EFFFF SA61 64K/32K 1E8000 - 1EFFFF <td></td>	
SA41 64K/32K 148000 - 14FFFF SA42 64K/32K 150000 - 15FFFF SA43 64K/32K 158000 - 15FFFF SA44 64K/32K 160000 - 16FFFF SA45 64K/32K 170000 - 17FFFF SA46 64K/32K 178000 - 17FFFF SA47 64K/32K 18000 - 18FFFF SA48 64K/32K 18000 - 18FFF SA49 64K/32K 19000 - 19FFF SA50 64K/32K 19000 - 19FFF SA51 64K/32K 198000 - 19FFF SA52 64K/32K 140000 - 1AFFFF SA53 64K/32K 18000 - 1BFFFF SA54 64K/32K 18000 - 1BFFFF SA55 64K/32K 18000 - 1BFFFF SA56 64K/32K 18000 - 1BFFFF SA57 64K/32K 1C0000 - 1CFFFF SA58 64K/32K 1D0000 - 1DFFFF SA59 64K/32K 1D0000 - 1EFFFF SA60 64K/32K 1E0000 - 1EFFFF SA61 64K/32K 1E0000 - 1EFFFF	
SA42 64K/32K 150000 - 157FFF SA43 64K/32K 158000 - 15FFFF SA44 64K/32K 160000 - 167FFF SA45 64K/32K 168000 - 16FFFF SA46 64K/32K 170000 - 17FFFF SA47 64K/32K 178000 - 17FFFF SA48 64K/32K 180000 - 18FFFF SA49 64K/32K 18000 - 18FFFF SA50 64K/32K 19000 - 19FFF SA51 64K/32K 198000 - 19FFF SA52 64K/32K 18000 - 1AFFFF SA53 64K/32K 1A0000 - 1AFFFF SA54 64K/32K 1B000 - 1BFFFF SA55 64K/32K 1B000 - 1BFFFF SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C0000 - 1CFFFF SA58 64K/32K 1D0000 - 1DFFFF SA59 64K/32K 1D0000 - 1E7FFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E0000 - 1E7FFF	
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SA44 64K/32K 160000 - 167FFF SA45 64K/32K 168000 - 16FFFF SA46 64K/32K 170000 - 177FFF SA47 64K/32K 178000 - 17FFFF SA48 64K/32K 180000 - 187FFF SA49 64K/32K 188000 - 18FFFF SA50 64K/32K 190000 - 197FFF SA51 64K/32K 198000 - 19FFFF SA52 64K/32K 1A0000 - 1A7FFF SA53 64K/32K 1A8000 - 1AFFFF SA54 64K/32K 1B0000 - 1B7FFF SA55 64K/32K 1B8000 - 1BFFFF SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C8000 - 1CFFFF SA58 64K/32K 1D0000 - 1D7FFF SA59 64K/32K 1D8000 - 1E7FFF SA60 64K/32K 1E8000 - 1E7FFF SA61 64K/32K 1E8000 - 1E7FFF SA62 64K/32K 1F0000 - 1F7FFF	
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SA48 64K/32K 180000 - 187FFF SA49 64K/32K 180000 - 18FFFF SA50 64K/32K 190000 - 197FFF SA51 64K/32K 198000 - 19FFFF SA52 64K/32K 1A0000 - 1A7FFF SA53 64K/32K 1A8000 - 1AFFFF SA54 64K/32K 1B0000 - 1BFFFF SA55 64K/32K 1B8000 - 1BFFFF SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C8000 - 1CFFFF SA58 64K/32K 1D0000 - 1DFFFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1E7FFF SA62 64K/32K 1F0000 - 1F7FFF	
SA49 64K/32K 188000 - 18FFFF SA50 64K/32K 190000 - 197FFF SA51 64K/32K 198000 - 19FFFF SA52 64K/32K 1A0000 - 1A7FFF SA53 64K/32K 1A8000 - 1AFFFF SA54 64K/32K 1B0000 - 1BFFFF SA55 64K/32K 1B8000 - 1BFFFF SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C8000 - 1DFFFF SA58 64K/32K 1D0000 - 1DFFFF SA59 64K/32K 1B0000 - 1EFFFF SA60 64K/32K 1E0000 - 1EFFFF SA61 64K/32K 1E8000 - 1FFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA50 64K/32K 190000 - 197FFF SA51 64K/32K 198000 - 19FFFF SA52 64K/32K 1A0000 - 1A7FFF SA53 64K/32K 1A8000 - 1AFFFF SA54 64K/32K 1B0000 - 1BFFFF SA55 64K/32K 1B8000 - 1BFFFF SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C8000 - 1CFFFF SA58 64K/32K 1D0000 - 1D7FFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA51 64K/32K 198000 - 19FFFF SA52 64K/32K 1A0000 - 1A7FFF SA53 64K/32K 1A8000 - 1AFFFF SA54 64K/32K 1B0000 - 1B7FFF SA55 64K/32K 1B8000 - 1BFFFF SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C8000 - 1CFFFF SA58 64K/32K 1D0000 - 1D7FFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA52 64K/32K 1A0000 - 1A7FFF SA53 64K/32K 1A8000 - 1AFFFF SA54 64K/32K 1B0000 - 1B7FFF SA55 64K/32K 1B8000 - 1BFFFF SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C8000 - 1CFFFF SA58 64K/32K 1D0000 - 1D7FFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1E7FFF SA62 64K/32K 1F0000 - 1F7FFF	
SA53 64K/32K 1A8000 - 1AFFFF SA54 64K/32K 1B0000 - 1B7FFF SA55 64K/32K 1B8000 - 1BFFFF SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C8000 - 1CFFFF SA58 64K/32K 1D0000 - 1D7FFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA54 64K/32K 1B0000 - 1B7FFF SA55 64K/32K 1B8000 - 1BFFFF SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C8000 - 1CFFFF SA58 64K/32K 1D0000 - 1D7FFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA55 64K/32K 1B8000 - 1BFFFF SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C8000 - 1CFFFF SA58 64K/32K 1D0000 - 1D7FFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA56 64K/32K 1C0000 - 1C7FFF SA57 64K/32K 1C8000 - 1CFFFF SA58 64K/32K 1D0000 - 1D7FFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA57 64K/32K 1C8000 - 1CFFF SA58 64K/32K 1D0000 - 1D7FFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA58 64K/32K 1D0000 - 1D7FFF SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA59 64K/32K 1D8000 - 1DFFFF SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA60 64K/32K 1E0000 - 1E7FFF SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA61 64K/32K 1E8000 - 1EFFFF SA62 64K/32K 1F0000 - 1F7FFF	
SA62 64K/32K 1F0000 - 1F7FFF	
SA63 8K/4K 1F8000 - 1F8FFF	
SA64 8K/4K 1F9000 - 1F9FFF	
SA65 8K/4K 1FA000 - 1FAFFF	
SA66 8K/4K 1FB000 - 1FBFFF	
SA67 8K/4K 1FC000 - 1FCFFF	
SA68 8K/4K 1FD000 - 1FDFFF	
SA69 8K/4K 1FE000 - 1FEFFF	
SA70 8K/4K 1FF000 - 1FFFFF	

26. DC and AC Operating Range

	AT49BV320D(T)-70	
Operating Temperature (Case)	Ind.	-40°C - 85°C
V _{CC} Power Supply		2.65V to 3.6V

27. Operating Modes

Mode	CE	ŌĒ	WE	RESET	V _{PP} ⁽¹⁾	Ai	I/O
Read	V_{IL}	V_{IL}	V _{IH}	V _{IH}	X ⁽²⁾	Ai	D _{OUT}
Program/Erase ⁽³⁾	V_{IL}	V_{IH}	V _{IL}	V _{IH}	V _{IHPP} ⁽⁴⁾	Ai	D _{IN}
Standby/Program Inhibit	V_{IH}	X ⁽²⁾	Х	V _{IH}	Х	X	High-Z
	Х	Х	V _{IH}	V _{IH}	Х		
Program Inhibit	Х	V _{IL}	Х	V _{IH}	Х		
	Х	Х	Х	V _{IH}	V _{ILPP} ⁽⁵⁾		
Output Disable	Х	V _{IH}	Х	V _{IH}	Х		High-Z
Reset	Х	Х	Х	V _{IL}	Х	X	High-Z
Product Identification				.,		A0 = V _{IL} , A1 - A20 = V _{IL}	Manufacturer Code ⁽⁶⁾
Software				V _{IH}		A0 = V _{IH} , A1 - A20 = V _{IL}	Device Code ⁽⁶⁾

Notes: 1. The VPP pin can be tied to V_{CC} . For faster program operations, V_{PP} can be set to 9.5V \pm 0.5V.

- X can be V_{IL} or V_{IH}.
 Refer to AC programming waveforms on page 26.
- 4. V_{IHPP} (min) = 1.65V.
- 5. V_{ILPP} (max) = 0.4V.
- 6. Manufacturer Code: 001FH, Device Code: 90C5H AT49BV320D; 90C4H AT49BV320DT



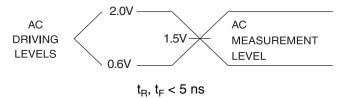


28. DC Characteristics

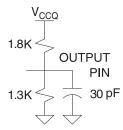
Symbol	Parameter	Condition	Min	Тур	Max	Units
ILI	Input Load Current	$V_{IN} = 0V \text{ to } V_{CC}$			2	μA
I _{LO}	Output Leakage Current	$V_{I/O} = 0V \text{ to } V_{CC}$			2	μA
I _{SB}	V _{CC} Standby Current CMOS	$\overline{\text{CE}} = \text{V}_{\text{CC}} - 0.3 \text{V to V}_{\text{CC}}$		15	25	μA
I _{CC} ⁽¹⁾	V _{CC} Active Read Current	f = 5 MHz; I _{OUT} = 0 mA		10	15	mA
I _{CC1}	V _{CC} Programming Current				25	mA
I _{PP1}	V _{PP} Input Load Current				10	μA
V _{IL}	Input Low Voltage				0.6	V
V _{IH}	Input High Voltage		V _{CCQ} - 0.6			V
V _{OL}	Output Low Voltage	I _{OL} = 2.1 mA			0.45	V
V _{OH}	Output High Voltage	I _{OH} = -100 μA	V _{CCQ} - 0.1			V

Note: 1. In the erase mode, I_{CC} is 25 mA.

29. Input Test Waveforms and Measurement Level



30. Output Test Load



31. Pin Capacitance

 $f = 1 \text{ MHz}, T = 25^{\circ}C^{(1)}$

Symbol	Тур	Max	Units	Conditions
C _{IN}	4	6	pF	V _{IN} = 0V
C _{OUT}	8	12	pF	V _{OUT} = 0V

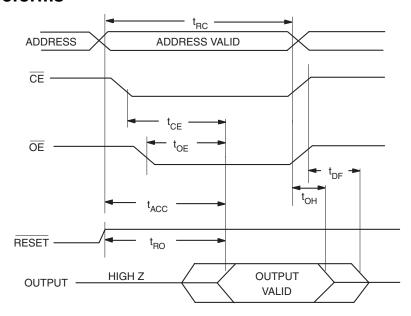
Note: This parameter is characterized and is not 100% tested.



32. AC Read Characteristics

		AT49BV3	AT49BV320D(T)-70			
Symbol	Parameter	Min	Max	Units		
t _{RC}	Read Cycle Time	70		ns		
t _{ACC}	Address to Output Delay		70	ns		
t _{CE} ⁽¹⁾	CE to Output Delay		70	ns		
t _{OE} ⁽²⁾	OE to Output Delay	0	20	ns		
t _{DF} ⁽³⁾⁽⁴⁾	CE or OE to Output Float	0	25	ns		
t _{OH}	Output Hold from \overline{OE} , \overline{CE} or Address, whichever occurred first	0		ns		
t _{RO}	RESET to Output Delay		100	ns		

33. AC Read Waveforms⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾



- Notes: 1. \overline{CE} may be delayed up to t_{ACC} t_{CE} after the address transition without impact on t_{ACC} .

 2. \overline{OE} may be delayed up to t_{CE} t_{OE} after the falling edge of \overline{CE} without impact on t_{CE} or by t_{ACC} t_{OE} after an address change without impact on t_{ACC} . 3. t_{DF} is specified from \overline{OE} or \overline{CE} , whichever occurs first (CL = 5 pF).

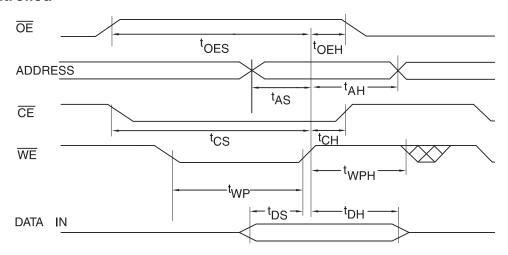
 - 4. This parameter is characterized and is not 100% tested.

34. AC Word Load Characteristics

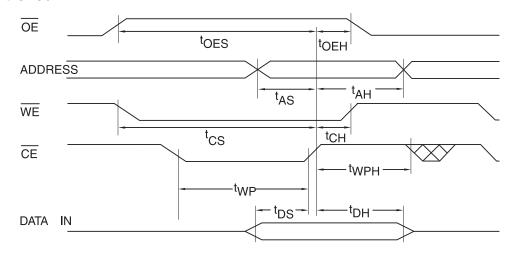
Symbol	Parameter	Min	Max	Units
t _{AS} , t _{OES}	Address, OE Setup Time	20		ns
t _{AH}	Address Hold Time	0		ns
t _{CS}	Chip Select Setup Time	0		ns
t _{CH}	Chip Select Hold Time	0		ns
t _{WP}	Write Pulse Width (WE or CE)	25		ns
t _{WPH}	Write Pulse Width High	15		ns
t _{DS}	Data Setup Time	25		ns
t _{DH} , t _{OEH}	Data, OE Hold Time	0		ns

35. AC Word Load Waveforms

35.1 WE Controlled



35.2 CE Controlled



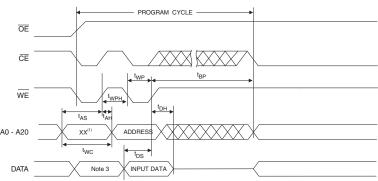




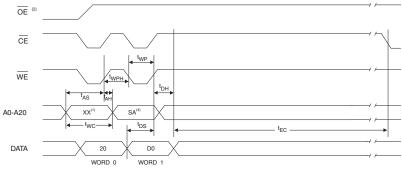
36. Program Cycle Characteristics

Symbol	Parameter	Min	Тур	Max	Units
t _{BP}	Word Programming Time		10	120	μs
t _{BPD}	Word Programming Time in Dual Programming Mode		5	60	μs
t _{AS}	Address Setup Time	20			ns
t _{AH}	Address Hold Time	0			ns
t _{DS}	Data Setup Time	25			ns
t _{DH}	Data Hold Time	0			ns
t _{WP}	Write Pulse Width	25			ns
t _{WPH}	Write Pulse Width High	15			ns
t _{WC} Write Cycle Time		70			ns
t _{RP}	Reset Pulse Width	500			ns
t _{SEC1}	Sector Erase Cycle Time (4K Word Sectors)		0.1	2	seconds
t _{SEC2}	Sector Erase Cycle Time (32K Word Sectors)		0.5	6.0	seconds
t _{ES}	Erase Suspend Time			15	μs
t _{PS}	Program Suspend Time			10	μs

37. Program Cycle Waveforms



38. Sector Erase Cycle Waveforms



Notes: 1. Any address can be used to load the data.

- 2. \overrightarrow{OE} must be high only when \overrightarrow{WE} and \overrightarrow{CE} are both low.
- 3. The data can be 40H or 10H.
- 4. The address depends on what sector is to be erased.

39. Common Flash Interface Definition Table

Address	AT49BV320DT	AT49BV320D	Comments	
10h	0051h	0051h	"Q"	
11h	0052h	0052h	"R"	
12h	0059h	0059h	"Y"	
13h	0003h	0003h		
14h	0000h	0000h		
15h	0041h	0041h		
16h	0000h	0000h		
17h	0000h	0000h		
18h	0000h	0000h		
19h	0000h	0000h		
1Ah	0000h	0000h		
1Bh	0027h	0027h	VCC min write/erase	
1Ch	0036h	0036h	VCC max write/erase	
1Dh	0090h	0090h	VPP min voltage	
1Eh	00A0h	00A0h	VPP max voltage	
1Fh	0004h	0004h	Typ word write – 10 μs	
20h	0002h	0002h	Typ dual word program time – 5 μs	
21h	0009h	0009h	Typ sector erase, 500 ms	
22h	0000h	0000h	Typ chip erase, not supported	
23h	0004h	0004h	Max word write/typ time	
24h	0004h	0004h	Max dual word program time/typ time	
25h	0004h	0004h	Max sector erase/typ sector erase	
26h	0000h	0000h	Max chip erase/ typ chip erase	
27h	0016h	0016h	Device size	
28h	0001h	0001h	x16 device	
29h	0000h	0000h	x16 device	
2Ah	0002h	0002h	Maximum number of bytes in multiple byte write = 4	
2Bh	0000h	0000h	Maximum number of bytes in multiple byte write = 4	
2Ch	0002h	0002h	2 regions, x = 2	
2Dh	003Eh	0007h	64K bytes, Y = 62 (Top); 8K bytes, Y = 7 (Bottom)	
2Eh	0000h	0000h	64K bytes, Y = 62 (Top); 8K bytes, Y = 7 (Bottom)	
2Fh	0000h	0020h	64K bytes, Z = 256 (Top); 8K bytes, Z = 32 (Bottom)	
30h	0001h	0000h	64K bytes, Z = 256 (Top); 8K bytes, Z = 32 (Bottom)	
31h	0007h	003Eh	8K bytes, Y = 7 (Top); 64K bytes, Y = 62 (Bottom)	
32h	0000h	0000h	8K bytes, Y = 7 (Top); 64K bytes, Y = 62 (Bottom)	
33h	0020h	0000h	8K bytes, Z = 32 (Top); 64K bytes, Z = 256 (Bottom)	
34h	0000h	0001h	8K bytes, Z = 32 (Top); 64K bytes, Z = 256 (Bottom)	





39. Common Flash Interface Definition Table (Continued)

Address	AT49BV320DT	AT49BV320D	Comments	
VENDOR SPECIFIC EXTENDED QUERY				
41h	0050h	0050h	"P"	
42h	0052h	0052h	"R"	
43h	0049h	0049h	" ["	
44h	0031h	0031h	Major version number, ASCII	
45h	0030h	0030h	Minor version number, ASCII	
46h	0086h	0086h	Bit 0 – chip erase supported, 0 – no, 1 – yes Bit 1 – erase suspend supported, 0 – no, 1 – yes Bit 2 – program suspend supported, 0 – no, 1 – yes Bit 3 – simultaneous operations supported, 0 – no, 1 – yes Bit 4 – burst mode read supported, 0 – no, 1 – yes Bit 5 – page mode read supported, 0 – no, 1 – yes Bit 6 – queued erase supported, 0 – no, 1 – yes Bit 7 – protection bits supported, 0 – no, 1 – yes	
47h	0000h	0001h Bit 8 – top ("0") or bottom ("1") boot sector device undefined bits		
48h	0000h	0000h	Bit 0 – 4 word linear burst with wrap around, 0 – no, 1 – yes Bit 1 – 8 word linear burst with wrap around, 0 – no, 1 – yes Bit 2 – continuos burst, 0 - no, 1 - yes Undefined bits are "0"	
49h	0000h	0000h	Bit 0 – 4 word page, 0 – no, 1 – yes Bit 1 – 8 word page, 0 – no, 1 – yes Undefined bits are "0"	
4Ah	0080h	0080h	Location of protection register lock byte, the section's first byte	
4Bh	0003h	0003h	# of bytes in the factory prog section of prot register – 2*n	
4Ch	0003h	0003h	# of bytes in the user prog section of prot register – 2*n	

40. Ordering Information

40.1 Green Package (Pb/Halide-free)

t _{ACC}	I _{cc}	; (mA)			
(ns)	Active	Standby	Ordering Code	Package	Operation Range
70	70 05 0005	AT49BV320D-70CU AT49BV320D-70TU	47C1 48T	Industrial	
70	25	0.025	AT49BV320DT-70CU AT49BV320DT-70TU	47C1 48T	(-40° to 85°C)

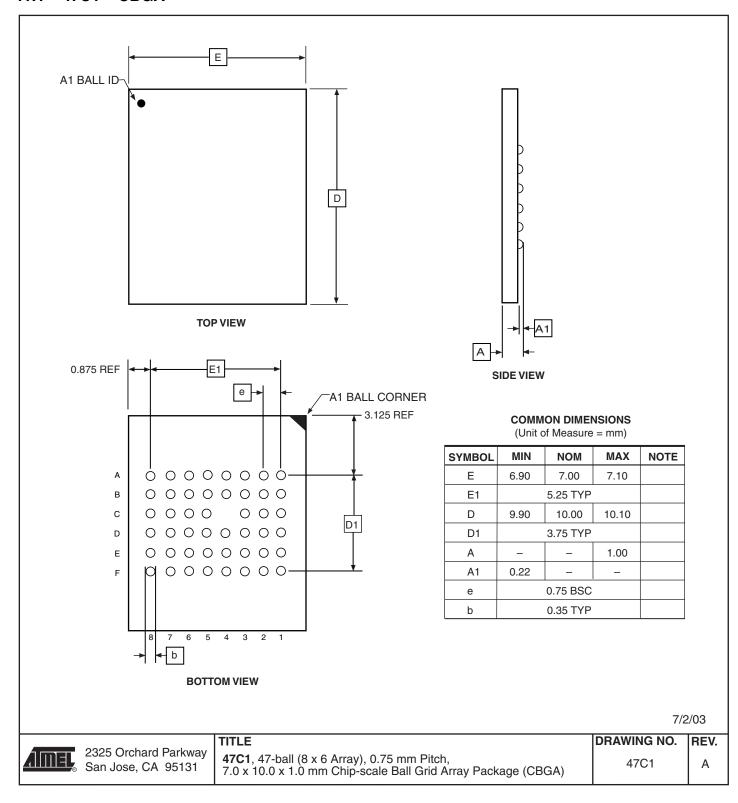
Package Type				
47C1	47C1 47-ball, Plastic Chip-Size Ball Grid Array Package (CBGA)			
48T 48-lead, Plastic Thin Small Outline Package (TSOP)				



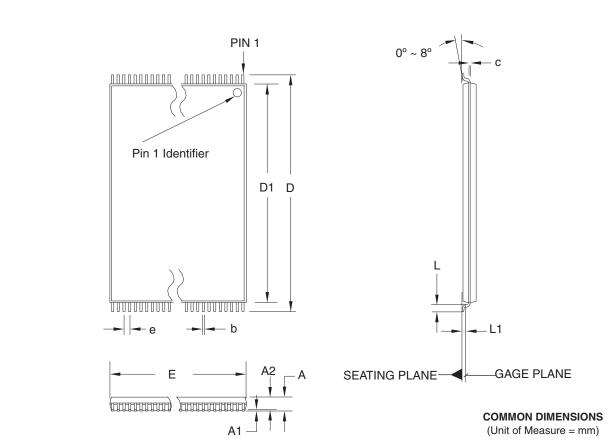


41. Packaging Information

41.1 47C1 - CBGA



41.2 48T - TSOP



Notes:

- This package conforms to JEDEC reference MO-142, Variation DD.
 Dimensions D1 and E do not include mold protrusion. Allowable protrusion on E is 0.15 mm per side and on D1 is 0.25 mm per side.
- 3. Lead coplanarity is 0.10 mm maximum.

SYMBOL	MIN	NOM	MAX	NOTE
Α	_	_	1.20	
A1	0.05	_	0.15	
A2	0.95	1.00	1.05	
D	19.80	20.00	20.20	
D1	18.30	18.40	18.50	Note 2
E	11.90	12.00	12.10	Note 2
L	0.50	0.60	0.70	
L1	0.25 BASIC			
b	0.17	0.22	0.27	
С	0.10	_	0.21	
е	0.50 BASIC			

10/18/01

L			
ſ			TITLE
	<u>AIMEL</u>	2325 Orchard Parkway San Jose, CA 95131	48T , Pack

48-lead (12 x 20 mm Package) Plastic Thin Small Outline kage, Type I (TSOP)

DRAWING NO.	REV.
48T	В





42. Revision History

Revision No.	History
Revision A – Sept. 2005	Initial Release
Revision B – Oct. 2005	 Added Top Boot version. Added Sector Address Table for the AT49BV320DT. Added CFI information for the AT49BV320DT. Modified Program Suspend/Resume Procedure on page 11 to match the flow chart. Modified Erase Suspend/Resume Procedure on page 13 to match the flow chart.
Revision C – Nov. 2005	 Added CBGA Package Option. Changed the CFI values of addresses 20h & 24h to 0002h and 0004h, respectively.
Revision D – Feb. 2006	Changed the AT49BV320DT CFI values of addresses 23h & 25h to 0004h and 0004h, respectively.



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